TOSHIBA Schottky Barrier Rectifier Stack Trench Schottky Barrier Type

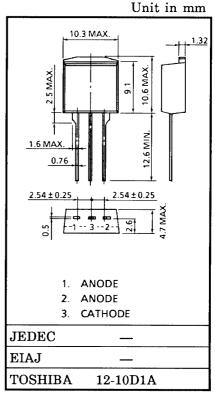
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Switching Type Power Supply Application **Converter & Chopper Application**

- Repetitive peak reverse voltage: VRRM = 120 V
- Peak Forward Voltage: $V_{FM} = 0.85 V (max)$
- Average output rectified current: IO = 30 A
- Low switching loses and output noise.

Maximum Ratings

Characteristics	Symbol	Rating	Unit	
Repetitive peak reverse voltage	V _{RRM}	120	V	
Average output rectified current	Ι _Ο	30	А	
Peak one cycle surge forward current (sine wave)	IFSM	250 (50 Hz)	А	
Junction temperature	Тј	-40~150	°C	
Storage temperature range	T _{stg}	-40~150	°C	



Weight : 0.74g

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Peak forward voltage	V _{FM}	I _{FM} = 15 A		_	0.85	V
Repetitive peak reverse current	I _{RRM}	V _{RRM} = Rated (120 V)	—	_	50	μA
Junction capacitance	Cj	$V_{R} = 10 V, f = 1.0 MHz$	_	227	_	pF
Thermal resistance	R _{th (j-c)}	DC Total	_		1.2	°C/W

Note: V_{FM}, I_{RRM}, C_j: A value of one cell.

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damage to property.
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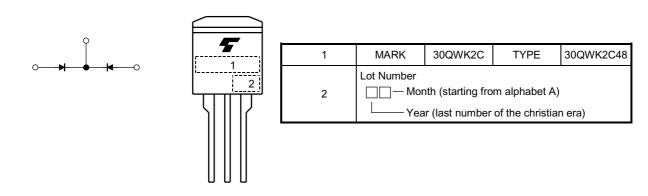
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Polarity

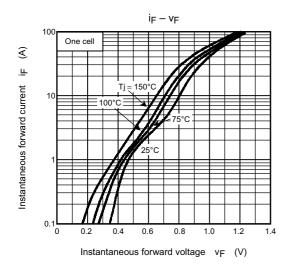
Marking

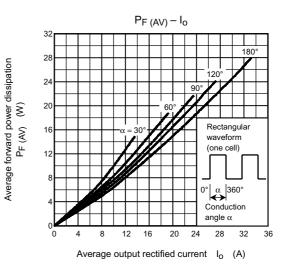


Handling Precaution

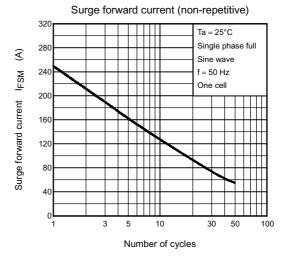
Schottky barrier diodes are having large-reverse-current-leakage characteristic compare to other rectifier products. This current leakage and not proper operating temperature or voltage may cause thermal run. Please take forward and reverse loss into consideration when you design.

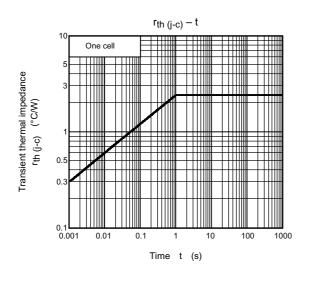
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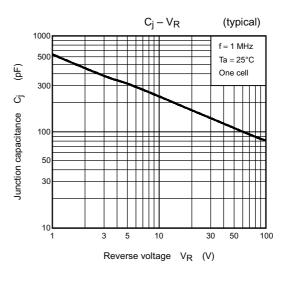




Tc max – I_o 14(Average forward power dissipation Tc max (°C) Rectangular waveform (one cell) 0° α Conduction angle α Average output rectified current Io (A)







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